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## Correction: Optical and electrical effects of plasmonic nanoparticles in high-efficiency hybrid solar cells

Wei-Fei Fu,<sup>a</sup> Xiaoqiang Chen,<sup>a</sup> Xi Yang,<sup>a</sup> Ling Wang,<sup>a</sup> Ye Shi,<sup>a</sup> Minmin Shi,<sup>a</sup> Han-Ying Li,<sup>a</sup> Alex K.-Y. Jen,<sup>ab</sup> Jun-Wu Chen,<sup>c</sup> Yong Cao<sup>c</sup> and Hong-Zheng Chen<sup>\*,a</sup>

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Correction for 'Optical and electrical effects of plasmonic nanoparticles in high-efficiency hybrid solar cells' by Wei-Fei Fu *et al.*, *Phys. Chem. Chem. Phys.*, 2013, 15, 17105–17111, DOI: 10.1039/C3CP52723A.

We found that Fig. 4 on page 17108 was not the correct figure for “Current density–voltage ( $J$ – $V$ ) characteristics (a) and the external quantum efficiency (EQE) (b) of the HSCs with different concentrations of Au NPs in PEDOT:PSS layer”; it was the same figure as Fig. 5 by mistake. The correct figure is shown below.

Please note that this Correction does not affect in any way the main conclusions of the paper.

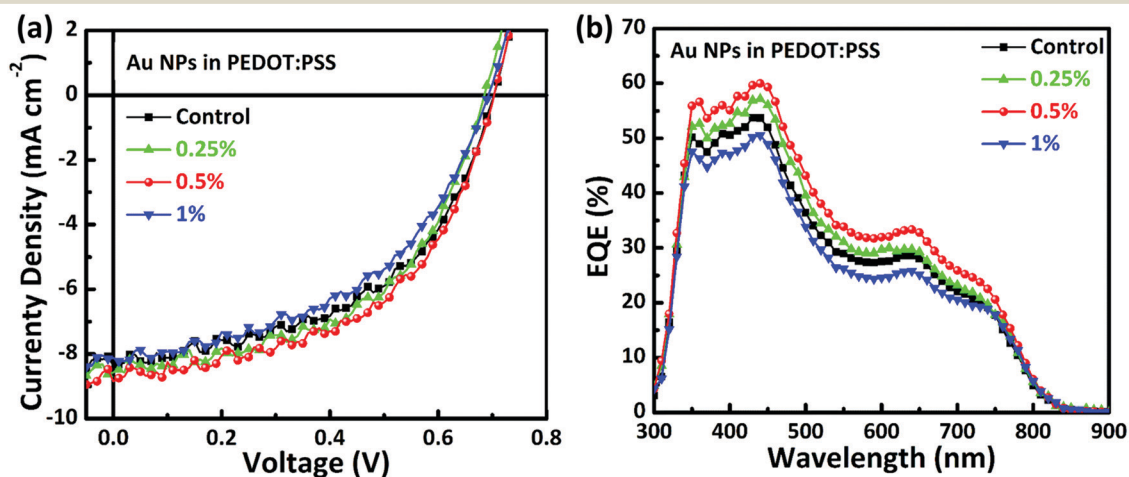


Fig. 4 Current density–voltage ( $J$ – $V$ ) characteristics (a) and the external quantum efficiency (EQE) (b) of the HSCs with different concentrations of Au NPs in the PEDOT:PSS layer.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

<sup>a</sup> State Key Laboratory of Silicon Materials, MOE Key Laboratory of Macromolecular Synthesis and Functionalization, & Department of Polymer Science and Engineering, Zhejiang University, Hangzhou 310027, P. R. China. E-mail: hzchen@zju.edu.cn; Fax: +86 571 87953733; Tel: +86 571 87952557

<sup>b</sup> Department of Materials Science and Engineering, University of Washington, Seattle, WA 98198, USA

<sup>c</sup> Institute of Polymer Optoelectronic Materials & Devices, State Key Laboratory of Optoelectronic Functional Materials & Devices, South China University of Technology, Guangzhou 510640, P. R. China

